Large-area high-efficiency perovskite solar cells based on perovskite films dried by the multi-flow air knife method in air†

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Perovskite solar cells are extremely promising high-efficiency low-cost photovoltaic devices. However, large-area and uniform perovskite film fabrication in air is still a big challenge for the mass production of highly efficient perovskite solar cells. Here, we first report the novel multi-flow air knife (MAK) method to control the formation of large-area perovskite films in ambient air. The proposed MAK method, based on the comprehensive understanding of the solution film evaporation process, entails the use of multiple gas flows that rapidly dry the solution and enable the production of large-area perovskite films in air. By adopting the MAK technology, high-quality films with full surface coverage and a low surface roughness of 4.98 nm over a 10×10 μm² scan area were successfully fabricated. Highly reproducible power conversion efficiencies up to 11.70% were achieved with an active area of 0.1 cm². The highest efficiency of 17.71%, obtained for a device with an area of 0.1 cm², further demonstrated the promising potential of this technology. Thus, the MAK technology enables the low-cost fabrication of highly efficient perovskite solar cells, paving the way for the mass production of low-cost high-performance perovskite solar cells in ambient air.

Introduction

Metal-halide perovskite solar cells have attracted enormous interest and extensive research due to the excellent achievements in the field of third generation photovoltaic devices, which focus on providing clean energy for humans in the future. Their power conversion efficiencies have skyrocketed from 3.8% (ref. 1) to values higher than 20% (ref. 2–4) in just about 5 years. Metal-halide perovskite is an outstanding photoabsorber and carrier transporter, owing to its high extinction coefficient, excellent ambipolar charge mobility, small exciton binding energy, and tunable bandgap.1–4 Perovskite solar cells can be easily and cheaply prepared by using solution processing methods through high-yield printing and coating technologies, which are attractive for low-cost large-area solar energy harvesting in industrial applications.

For scaling-up and commercialization of perovskite-based devices, the continuous fabrication of pinhole-free perovskite films in air is crucial. However, to date, this is a great challenge due to the lack of a clear understanding of the precipitation process of solid perovskite from a solution. Notably, a good delivery efficiency in perovskite solar cells essentially depends on a compact pin-hole free perovskite film, which can lead to excellent electrical performances.5 As a crucial layer, the perovskite film is widely prepared by solution processing methods, and great achievements have led to highly efficient solar cells.6–13 The active device area has also increased from 0.035,14 0.04,15 and 0.09 cm²,16 to 1 cm²,17,18 which is a groundbreaking value and accelerates industrial application. However, large-area perovskite film fabrication in air is still a great challenge. High-cost vacuum technology can hardly produce high-quality perovskite films over large areas,19,20 and thus, for perovskite solar cell industrialization, large-area films prepared in ambient air are necessary.

To fabricate high-quality perovskite films, various thin-film deposition technologies including spray deposition,21 spin coating,22,23 doctor blading,21,24 printing,25,26 and slot-die coating27 have been adopted. In our previous study, we proposed a gas pump method to produce full-coverage perovskite films, reporting 19% efficiency for devices on rigid glass and 11.34% efficiency for devices on a plastic substrate.28–30 Recently, a certified efficiency of 19.6% for devices fabricated by using this method (named as vacuum flash-assisted solution process) was reported.31 Although highly compact perovskite films cannot be fabricated by using only solution deposition technologies, the film drying process enables the critical formation of a solid pin-hole-free film upon precipitation of solid perovskite from a supersaturated solution. However, our current understanding of the phenomena occurring during the
The drying process of a large-area solution film is considerably limited.

In this paper, we report for the first time the multi-flow air knife (MAK) method, which can be used to prepare large-area high-performance perovskite films at room temperature in ambient air. We also report a record efficiency of 11.70% for large-area perovskite solar cells (with an active area of 1 cm²) fabricated by using the MAK method in ambient air. We successfully fabricated a full-coverage perovskite film with a surface roughness of 4.98 nm on a 10 × 10 μm² scan area, as measured via atomic force microscopy (AFM). The grains appeared uniform and close packed in the whole film. Planar perovskite solar cells were also fabricated with perovskite films, prepared by the MAK method, on 2.5 × 2.5 cm² substrates, and efficiencies as high as 11.70% and 17.71% were obtained for active areas of 1 and 0.1 cm², respectively. The devices showed good reproducibility due to excellent film quality. Device efficiencies of 10.20% ± 0.81% and 14.42% ± 1.34% were averaged over 40 solar cells with active areas of 1 cm² and 0.1 cm², respectively. We believe that the MAK method would promote the low-cost fabrication of highly efficient perovskite solar cells, paving the way for mass production of low-cost high-performance perovskite solar cells in ambient air.

Experimental section

Materials and preparation

Lead iodide (PbI₂, 99.99%), N,N-dimethylformamide (DMF, 99.8%), iodine methylamine (CH₃NH₃I), and 2,2,7,7-tetra-1H,3H-di-p-methoxyphenylamine)-9,9-spirobiotriptycene (Spiro-OMeTAD) were purchased from Xi’an Polymer Light Technology Corp. Titanium dioxide precursor solvent was synthesized in our group. Lead iodide (PbI₂, 99.99%), N,N-dimethylformamide (DMF, 99.8%), iodine methylamine (CH₃NH₃I), and 2,2,7,7-tetra-1H,3H-di-p-methoxyphenylamine)-9,9-spirobiotriptycene (Spiro-OMeTAD) were purchased from Xi’an Polymer Light Technology Corp. Titanium dioxide precursor solvent was synthesized in our group.

Perovskite film fabrication

PbI₂ and CH₃NH₃I at a molar ratio of 1:1 were dissolved in DMF solvent. The perovskite precursor solution was stirred at 70 °C for 12 h and stored in a glovebox. An appropriate amount of perovskite precursor solution was dropped on the TiO₂-coated FTO surface and spun at 5000 rpm for 6 s; a faint yellow liquid perovskite precursor film of ~2 μm in thickness was obtained. Subsequently, the MAK was quickly swept across the solution film at the fastest air flow rate. In this paper, we adopted the flow rate values of 150, 225, and 300 L min⁻¹, using some different comparative distances between the MAK and the solution film surface (0.5, 1, 2, 3, 4, and 5 mm). The dried films were annealed for 10 min at 100 °C on a hot plate.

Perovskite solar cell fabrication

Devices were fabricated on FTO-coated glass (Pilkington, 15 Ω sq⁻¹). The FTO substrates were rinsed successively with acetone, ethyl alcohol, and deionized water in an ultrasonic bath for 10 min, and then blow dried with nitrogen. The FTO substrates were treated with ozone and ultraviolet light for 15 min. An electron transport layer of compact TiO₂ was deposited by spin coating a mildly acidic solution of titanium isopropanoxide in ethanol at 3000 rpm for 30 s, and sintered at 500 °C for 30 min. The hole-blocking layer of the compact TiO₂ layer was ~50 nm thick. A dense perovskite film was prepared by the MAK method, ~300 nm in thickness, on the TiO₂ layer. All the above steps were conducted under ambient conditions at a temperature of 20 ± 3 °C and humidity of 40 ± 5%. A spiro-OMeTAD solution (25 μL) was spin coated on perovskite films at 3000 rpm for 30 s. Devices were then left overnight in air to allow for the spiro-OMeTAD doping via oxidation. Finally, an 80 nm-thick Au layer was deposited by thermal evaporation under a vacuum of 4 × 10⁻⁴ Pa. The finished devices were stored in a N₂-purged glovebox (~0.1 ppm O₂ and H₂O) before measurement.

Results and discussion

Fabrication of large-area perovskite films by the MAK method

The general application of the MAK method to produce full-coverage large-area perovskite films is shown in Fig. 1a. First, a perovskite precursor solution is coated, for example by slot-die
or doctor-blading technology (or spin coating in a lab), on a TiO2-coated substrate to form a solution film with a light yellow color. Second, the solvent in the film is dried by sweeping the MAK from one side of the substrate to the other. Finally, the dried perovskite film is heated for 10 min. The dried perovskite film prepared by using the MAK method presented a mirror-like morphology with a black brown color. The large block substrate can then be cut into small pieces of 2.5 × 2.5 cm² (Fig. 1b), which are subsequently used to fabricate perovskite solar cells.

The film, further analyzed by scanning electron microscopy (SEM, Fig. 1d), clearly appeared compact and free of pin holes over the whole area. The grain size distribution was quite uniform. The statistical results revealed that the grains had a size of ~262 nm. As seen in the SEM image, flat polygonal grains with triple junction grain boundaries were the predominant microstructural feature, which suggested close packing of perovskite grains over the whole area.

Fig. 1c shows the cross-sectional schematic diagram of the MAK setup. When the MAK moves quickly on the liquid surface, multiple air flows from different channels sweep across the solution film surface with a certain speed, removing the solvent molecules away through air out. After the MAK sweeps over the whole solution film, a solid perovskite film is precipitated. The cross-sectional image showed a compact film made of closely packed columnar crystals (Fig. 1e). The MAK setup is flexible, and it allows sufficient air blowing over a short distance to dry the solution film. Moreover, the solution film size has no limitations, for example, a meter scale system for industrialization would be quite easy to realize.

To demonstrate the high performance of the produced perovskite film, planar perovskite solar cells were fabricated with the structure shown in Fig. 1f, obtaining a 17.02% efficiency with an active area of 0.1 cm² (Fig. 2a). The open-circuit voltage ($V_{oc}$) was 1.05 V, short-circuit current ($I_{sc}$) was 22.72 mA cm⁻², and fill factor (FF) was 0.71. To determine a more realistic efficiency of the device by considering the hysteresis effect, a steady-state photocurrent was measured as a function of time at the forward bias of 0.82 V, which corresponds to the maximum power output according to the current–voltage (I–V) measurement (Fig. 2b).

Under 1 sun continuous illumination, the steady-state photocurrent density stabilized at 20.05 mA cm⁻², and the power conversion efficiency (PCE) stabilized at 16.44% over 150 s, which was slightly lower (3%) than the PCE obtained from the I–V measurement.

Air-assisted flow has been previously used to dry liquid perovskite films, although it can’t be suitable for drying large-area solution films in ambient air. The solution films with areas of 5 × 5 cm² dried by air flow showed inhomogeneous morphologies, turning from shiny to blurry, and some wave traces can be observed in macroscopic pictures. This corresponds to the transition from uniform isometric to thick dendritic crystals observed in microscopic pictures (Fig. S1a†). The change is attributed to the fact that the solubility of the air flow rapidly reaches saturation when the flow sweeps across a solution film at a very short distance along the flowing direction (parallel to the surface in this case), and the flow gives rise to waves on the liquid film surface. The saturated flow, which contains evaporated solvent molecules, cannot dissolve more molecules. Essentially, the reported air assisted methods are based on axis asymmetry, and therefore can’t be successful for scale enlargement. In addition, a large distance between blowing air and the solution film hinders the diffusion of solvent molecules. As a result, the solution film cannot be thoroughly dried in a short time, as shown in Fig. S1b.†

To solve this crucial problem, in this study, we developed the MAK technique, which involves blowing air vertically on the liquid film surface. It avoids the formation of waves on the liquid film surface. In this method, the saturated air on the surface of the solution film is removed in a timely fashion through air out, while, at the same time, fresh air is constantly flowed in. Such a circulation process facilitates the quick removal of the solvent by fresh air. The solution film (area of 5 × 5 cm²) dried by using the MAK method exhibited a mirror-like black brown morphology, as shown in the photograph in Fig. S2.† To develop compact large-
Understanding the essence of solvent evaporation

To better understand the evaporation phenomenon in thin solution films, the prerequisites for solvent evaporation were thoroughly researched. In perovskite precursor solutions, N,N-dimethylformamide (DMF) is typically used as the organic solvent. The evaporation process of DMF in a closed space from the starting state (consisting of a DMF film and a fresh gas phase) to the complete evaporation state is shown in Fig. S3.† A critical gas thickness is a prerequisite (necessary condition) for the complete evaporation of the liquid DMF film. With this critical gas thickness, the liquid DMF film completely evaporates to its gas phase in air mixing with other gases until the partial pressure of DMF gas reaches the saturated vapor pressure at the current temperature in the gas mixture. Actually, only if the gas thickness is equal to or larger than this critical thickness, the liquid phase can completely evaporate. To obtain the critical thickness of the gas mixture at which all solvents have completely evaporated, some calculations were conducted as follows. Based on mass conservation of DMF between the starting liquid state and the final gaseous state, eqn (1) can be introduced:

$$A\delta\rho_i\% = \frac{AH\rho_i^*}{RT}M$$

then, $H$ can be expressed as in eqn (2):

$$H = \rho_i^*\%RT \frac{\delta}{P^*M}$$

where $A$ is the solution film area, $\delta$ is the solution film thickness, $\rho_i$ is the density of the precursor solution, $\%$ is the mass fraction of the DMF solvent in solution, $H$ is the gas mixture thickness, $P^*$ is the DMF saturated vapor pressure at the current temperature, $R$ is the gas constant, $T$ is the current temperature, and $M$ is the molar mass of DMF.

To achieve effective and complete solvent evaporation, a sufficient condition should also be satisfied. Evaporation is a process that involves two consecutive steps. The first step entails the evaporation of gas molecules from the solution surface, while the second step involves their transportation far away from the solution surface by diffusion. It can be first analyzed from a microscopic point of view, according to which gas molecules evaporate from the liquid phase. Notably, evaporation is a ubiquitous physical phenomenon involving mass transfer from a liquid phase to a gas phase. Classical evaporation theory gives eqn (3) based on the hypothesis that the gas satisfies the equation of state of an ideal gas and that evaporation and condensation are independent at the gas–liquid interface:36,37

$$j = j_e - j_\text{cond} = \left(\frac{M}{2\pi R}\right)^{\frac{1}{2}}\left(\frac{P_i}{\sqrt{T_i}} - \frac{P_g}{\sqrt{T_g}}\right)$$

where $j$ is the net mass flow rate, $j_e$ is the evaporation/condensation mass flow rate, $M$ is the molar mass, $P_i$ is the saturated vapor pressure at the current temperature, $T_i$ is the liquid temperature, $P_g$ is the partial pressure of the evaporated gas phase, and $T_g$ is the gas temperature. Apparently, $j$ depends on the difference between $P_i$ and $P_g$, since $T_i$ is generally equal to $T_g$. Therefore, reducing $P_g$ provides an effective way to increase the net evaporation mass flow rate from a microscopic point of view.

From a macroscopic point of view, evaporated molecules diffuse to far distance where the solvent partial pressure approaches zero. Diffusion depends on the concentration gradient $d$ (eqn (4)):

$$d = \frac{\partial C}{\partial h} = \frac{\Delta P}{h}$$

where $C$ is the solvent gas concentration, $h$ is the distance to the liquid surface, and $\Delta P$ is the difference of partial pressures at the liquid surface and bulk environment. It is known that evaporated solvent molecules can diffuse quickly at a large concentration gradient. In brief, a fast evaporation can be successfully conducted by significantly reducing $P_g$ and decreasing $h$.

Comparing different drying methods may help understand more deeply the evaporation process in thin solution films. Natural drying involves the drying of the solution film in its current environment (Fig. 3a). In this case, the net evaporation is very low because most of the gas molecules at the interface return to the liquid phase upon molecular collision. Obviously, in natural drying, the concentration gradient $d$ is extremely small (Fig. 3e), owing to the large $h$ value, and therefore, diffusivity is extremely low. Owing to the slow evaporation, small areas reaching supersaturation—which is necessary for nucleation—are formed on the solution film. Subsequently, the solute nucleates on those areas.38,39 Additionally, the low evaporation rate facilitates the migration of residual solute and formation of overgrown crystals.21 Finally, those nuclei grow into a light gray film with large roughness, visible to the naked eye (Fig. 3i). Fig. 3m shows a SEM image and schematic diagram of prismatic nucleation and growth. The film presented a disorganized branch-like morphology with long strip-like grains up to hundreds of micrometers in size, consistent with the results widely reported in the literature.40

Compared with natural drying, appropriate heating can accelerate solvent evaporation (Fig. 3b), as already reported.41 Heating promotes molecule diffusion, which results from a larger concentration gradient than that observed in natural drying because of the enlarged $\Delta P$ value (Fig. 3f). Therefore, more nuclei form on the substrate in a shorter time, growing into thick dendritic grains with sizes tens of micrometers larger (Fig. 3n) than those of the grains observed after natural drying. Correspondingly, the photograph in Fig. 3j displays a deeper gray color and a relatively smoother surface than the sample obtained by natural drying.

Intuitively, blowing air on the surface of a solution film favors the evaporation. The air flow can remove the gas molecules from the solution film surface, reducing the gas solvent partial pressure, $P_g$, thereby improving the net evaporation mass. Air-assisted evaporation conducted from a large distance...
from the liquid surface (Fig. 3c) removes some gas molecules and reduces $P_g$, while $d$ increases owing to the reduction in $h$ (Fig. 3h). Compared with the heat-dried film, some improvements were achieved, the film presented a dark gray color (Fig. 3k), and the dendritic grain size decreased by several micrometers (Fig. 3o). However, many pin holes, which are detrimental for the device performance, still existed in the film.

Remarkably, the MAK method provides a qualitative improvement in solvent evaporation, allowing the fabrication of extremely compact films. Due to the MAK blowing in close proximity of the surface, the vast majority of the molecules are effectively removed (Fig. 3d), resulting in a diffusion concentration gradient considerably higher than those observed for all the above mentioned methods (Fig. 3h). The MAK method allows a significant concentration gradient for diffusion of the evaporated solvent molecules. Consequently, the solvent evaporates instantaneously and uniform nuclei are formed on the substrate. Then, the nuclei grow competitively into closely arranged grains with sizes of hundreds of nanometers (Fig. 3p). The MAK-dried film obviously presented different features from the others, and exhibited a mirror-like black brown morphology (Fig. 3l). In brief, the flexible MAK method can tremendously facilitate the solution evaporation and molecule diffusion, allowing an adequate air blow from a short distance to dry the solution film. Besides, the solution film size is unlimited. Thus, industrialized manufacturing at the meter scale can be easily realized by concurrently adjusting the length of the air knife to the meter scale.

To explore the effects of film morphology on device performance, the four different kinds of films described above were

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**Fig. 3** Liquid N,N-dimethylformamide film evaporation under different drying conditions. (a–d) Schematic diagram showing molecule evaporation at the gas–liquid interface for natural, heat, air-assisted, and MAK drying, respectively. (e–h) Concentration gradients with molecule diffusion for natural, heat, air-assisted, and MAK drying, respectively. (i–l) Photographs of natural, heat, air-assisted and MAK dried films, respectively. (m–p) Scanning electron microscopy images and (insets) schematic diagrams of nucleation of natural, heat, air-assisted, and MAK dried liquid perovskite films, respectively.
used to prepare distinct devices, whose efficiencies showed significant differences (Fig. S4†). The device containing the naturally dried film achieved 0.89% efficiency, whereas a slightly higher efficiency (1.48%) was obtained for the device employing the heat-dried film. The device with the film dried by using an air-assisted procedure reached 8.72% efficiency, whereas an extremely high efficiency of 17.26% was achieved by the device using the MAK-dried film. The device efficiency improved greatly with film coverage rate increasing. The device energy conversion efficiency can be attributed to incomplete surface coverage resulting from cell shunting and poor light absorption.8–10

Crystallization and optical properties of the perovskite film

The MAK-dried perovskite film was examined by X-ray diffraction (XRD) to investigate its crystallization (Fig. 4a). Clear diffraction peaks at 14.08°, 28.40°, and 31.83° could be assigned to the (110), (220), and (310) planes, respectively, revealing the presence of the CH3NH3PbI3 tetragonal phase (space group I4/mcm, a = b = 8.8743 Å, and c = 12.6708 Å). No diffraction peaks of PbI2 or CH3NH3I were found in the pattern of the CH3NH3PbI3 crystals, indicating that the entire compound reacted completely during the MAK drying process.

To evaluate the optical properties of the perovskite film, the ultraviolet-visible absorption and photoluminescence (PL) spectra (Fig. 4b) were analyzed. The spectra exhibited very high absorption in the visible range of 380–760 nm, showing remarkable intensity at ~500 nm, which is consistent with the results reported in the literature.44,45 The static PL spectrum, excited at the wavelength of 560 nm, showed strong intensity at the wavelength of ~780 nm, in good agreement with previous results.46 The excellent optical properties may be probably ascribed to the low defect density in the bulk of the perovskite film.

Dependence of perovskite film quality on processing parameters

To investigate the quantitative relationship between the perovskite film microstructure and the processing parameters, perovskite films dried by using the MAK method were prepared by controlling two main processing parameters, i.e., air flow and distance between the air knife and the liquid surface. After being dried at 300 L min⁻¹ and 1 mm (air flow rate and distance between the air knife and the solution film surface, respectively), at the current temperature, the dried perovskite film appeared black-brown transparent with a mirror-like surface. When the air flow rate was lower than 300 L min⁻¹ or the distance higher than 1 mm, the dried perovskite film became blurry and opaque, as shown by the photographs in Fig. S5.† To investigate quantitatively their microscopic morphology and surface roughness, the MAK-dried perovskite films were measured by SEM and high-resolution AFM (Fig. 5). The measurement was performed on a randomly chosen large and uniform perovskite film. The AFM scanning area was 10 x 10 μm².

First, the influence of the air flow on film morphology was analyzed. Upon increasing the air flow at the distance of 1 mm, the perovskite films acquired a more compact and smooth morphology. Fig. 5a shows the morphology of the film dried at 150 L min⁻¹; large rod-like grains and some pin holes were visible, while the cross-sectional image showed the bare substrate, revealing incomplete perovskite coverage. The film root-mean-square (RMS) roughness was 21.28 nm, as shown by the AFM morphology (Fig. 5b). Fig. 5c shows the three-dimensional morphology and roughness fluctuation profile along the line in Fig. 5b. The large fluctuation indicated that the surface of the film was seriously coarse. By increasing the air flow to 225 L min⁻¹, the film exhibited smaller dendrite grains and a reduced number of pin holes, while the cross-sectional image showed an irregular cross-section (Fig. 5d). The film had a RMS of 15.0 nm, showing a smaller fluctuation than the film dried at 150 L min⁻¹ (Fig. 5e and f). Interestingly, when the air flow increased to 300 L min⁻¹, the perovskite film showed an extraordinarily compact and pin-hole free morphology (Fig. 5g). The grains, shown in the cross-sectional image, appeared as columnar crystals having a regular and close arrangement. The extremely smooth film RMS was only 4.98 nm (Fig. 5h). The slight fluctuation on the film surface was just in the range of 20 nm, significantly lower than the thickness of the compact film, ~300 nm (Fig. 5i). The examination was also conducted randomly over a large area of 20 x 20 μm², finding an RMS of 5.03 nm (Fig. S6†). Thus, air flow of sufficient rate can efficiently remove DMF molecules, significantly reducing the Fg value, accelerating the evaporation, and thus producing a full-coverage perovskite film.

Subsequently, we further examined the influence of the distance between the air knife and the liquid surface on the film morphology. The perovskite film was dried at the distance of 5 mm, using an air flow rate of 300 L min⁻¹. The analyses of both the surface and cross-sectional morphologies showed a film with small rod-like grains along with the bare substrate (Fig. 5j). The film had an RMS of 39.6 nm and a fluctuation (Fig. 5k and l) significantly larger than the film dried at the distance of 1 mm by using the same air flow rate. The smaller concentration gradient over a long distance cannot remove more molecules because of the difficult diffusion. The distance of 5 mm between the MAK and the solution film surface resulted in an air flow speed slower than that observed in the case of the distance of 1 mm at the same air flow rate. Therefore,
the perovskite film could not be properly dried at a large distance. A large concentration gradient is crucial to achieve a quick evaporation. The MAK method is highly efficient in drying perovskite films when using an appropriate air flow in close proximity.

Besides, more detailed experiments confirmed the above conclusions. The comparative results are shown in Fig. S7.† The perovskite film showed small pin holes and an isometric crystal morphology when dried at 150 L min⁻¹ and 1 mm, as shown in Fig. S7a.† When the distance increased to 1 mm, the perovskite film exhibited pin holes and dendritic structures of larger sizes, as shown in Fig. S7b.† Similarly, a change was also observed when the film was dried at 225 L min⁻¹, as shown in Fig. S7c and d.† This film presented smaller pin holes and shorter dendritic structures than that dried at 150 L min⁻¹ at the same distance. Fig. S7e–i† show the film dried at 300 L min⁻¹ with distances ranging from 1 to 5 mm, respectively. The perovskite film dried at a close distance exhibited a compact pin-hole free morphology with uniform isometric crystals. Upon increasing the distance, some pin holes appeared, and their size and number increased dramatically. Crystalline grains also transformed from uniform compact
isometric to large dendritic crystals. The larger the distance between the MAK and the liquid surface, the larger the dendritic structure. Finally, the perovskite film presented a discontinuous morphology. An adequate air flow can remove more solvent molecules at a short distance, producing a larger concentration gradient. Therefore, a compact pin-hole free perovskite film can be obtained by using suitable parameters, for example an air flow rate of 300 L min⁻¹ and a distance of 1 mm.

**Photovoltaic performance of perovskite solar cells**

To investigate the effects of the MAK-dried perovskite film morphology on the device performance, planar heterojunction perovskite-based solar cells were fabricated with active areas of 1 and 0.1 cm². Each small piece of perovskite-coated substrate was cut from a larger perovskite film prepared by using the MAK method. Upon analysis of over 40 devices with an active area of 1 cm², the highest efficiency was 11.70%, while the average efficiency was 10.20 ± 0.81%. Even higher efficiency was achieved for small-area devices, upon measuring 40 devices with an active area of 0.1 cm², the highest efficiency of 17.71% and average efficiency of 14.42 ± 1.34% were found. Clearly, this demonstrated the promising potential of this technology for the production of highly efficient perovskite solar cells.

Fig. 6a shows the cross-sectional SEM image of the devices. The structure consisted of a fluorine-doped tin oxide (FTO) coated glass, TiO₂ compact layer, MAK-dried CH₃NH₃PbI₃ perovskite absorber, spiro-OMeTAD hole transport layer, and thermally evaporated Au contact (FTO/TiO₂/CH₃NH₃PbI₃/spiro-OMeTAD/Au). Fig. 6b shows the corresponding energy levels for every layer. All layers were fabricated and characterized in an ambient atmosphere except for the thermally evaporated Au cathode. The best cells with efficiencies of 11.70% and 17.71% were fabricated with perovskite films dried at 300 L min⁻¹ and 1 mm. Fig. 6c shows the I–V curves of the best device (area of 1.0 cm²). The Voc was 1.09 V (which is comparable to the Voc values of the top-performing large-area devices based on the same materials), while Jsc was 17.62 mA cm⁻², FF was 0.612, and PCE was 11.70%. Fig. 6d shows the corresponding incident photon-to-current conversion efficiency (IPCE) spectrum and the integrated current density as a function of the wavelength. The integrated Jsc calculated from the IPCE spectrum, was 15.46 mA cm⁻², which was roughly comparable with that obtained from the I–V curves. Furthermore, perovskite solar cells with an active area of 0.1 cm² reached the highest efficiency of 17.71% (the I–V curves are shown in Fig. 6e), while Jsc was 23.50 mA cm⁻², Voc was 1.09 V, and FF was 0.69. To investigate the carrier transport and recombination behaviors in this device, electrochemical impedance spectroscopy (EIS) analysis was conducted. Fig. 6f shows the Nyquist plots over the frequency range from 4 MHz to 100 mHz at the forward bias range of 0.0–1.0 V and illumination of 37 W m⁻². Subsequently, the Nyquist plots were fitted using the RC equivalent circuit diagram, as shown in the inset of Fig. 6f. Notably, two distinct arcs could be observed in two distinct frequency regions in each EIS spectrum. The first arc in the high-frequency region is usually attributed to the carrier transport process at the interface in the device, while the second arc at low frequency is usually related to the charge recombination within the perovskite film and the interface of the charge transport layer. By increasing the forward bias, the two arcs became larger, which indicated increases in carrier transport and recombination resistances.

Furthermore, a large active area device of 1.47 cm² with the same size mask was measured. The high efficiency is up to 11.12%, as shown in Fig. S8. And the MAK method showed good reproducibility due to the well-controlled film quality. The average efficiency reached stably a value of 10.20 ± 0.81% for 40 solar cells with an active area of 1 cm² and 14.42 ± 1.34% for 40 solar cells with an active area of 0.1 cm². The device parameter distributions are shown in Fig. S9. All those cells showed high Voc and the highest Voc value, obtained for the cell with an area of 1 cm², was 1.10 V, which is the highest value obtained for devices with an area of 1 cm² fabricated with the same materials. The average Voc for 40 solar cells with an area of 1 cm² was 1.05 ± 0.03 V, which indicated the formation of a full-coverage compact perovskite film upon drying by using the MAK method over a large active area. Similarly, the highest Voc and average Voc values for 40 solar cells with an area of 0.1 cm² were 1.09 V and 1.05 ± 0.02 V, respectively. Statistically, 97.5% of the cells exhibited a Voc higher than 1 V. Thus, the MAK method is extremely valuable to prepare perovskite films in a scalable size.
In addition, some comparative experiments were also conducted with perovskite films dried by using different air flow rates and distances. The device parameters are reported in Tables S1 and S2. Clearly, devices using compact perovskite films dried at 300 L min\(^{-1}\) and 1 mm presented excellent electrical performances. This can be attributed to the fact that the defects in the perovskite film reduce the light absorption ability and increase the recombination at the interface between the electron transport layer and the hole transport layer. In addition, pin holes, or even the bare substrate without perovskite coverage, would inevitably reduce current shunting in the carrier transport, degrading the device performance.

**Conclusions**

In summary, we first demonstrated the fabrication of highly efficient perovskite solar cells based on perovskite films dried by using the novel MAK technology at room temperature in ambient air. We reported a record efficiency of 11.70% for large-area perovskite solar cells (active area of 1 cm\(^2\)) at room temperature in ambient air. By adopting the MAK method, we produced uniform, pin-hole free, large crystal grain size and rough-border-free perovskite films with a RMS of 4.98 nm. This method is highly efficient for drying solution films without any limitation on solvent and film size, and therefore can be easily applied to large-area meter-scale industrial mass production. Planar perovskite solar cells with an active area of 1 cm\(^2\) containing the fabricated films exhibited the highest efficiency of 11.70%. The devices also showed excellent reproducibility due to the high-quality films, reaching the average efficiency of 10.20% ± 0.81% over 40 solar cells. In addition, for the device with an active area of 0.1 cm\(^2\), the highest efficiency of 17.71% was obtained, which further suggested the promising potential of the MAK technology. We believe that the novel MAK method will tremendously promote the low-cost mass production of highly efficient perovskite solar cells, also providing a broad view for fabricating high-quality perovskite films by adopting alternative solution processes.

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**Notes and references**

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